Power transistor (60V, 3A)

2SC5826

Features

- 1) High speed switching.
- (Tf:Typ.:30ns at Ic = 3A)
- 2) Low saturation voltage, typically (Typ. : 200mV at $I_{C} = 2A$, $I_{B} = 0.2mA$)
- Strong discharge power for inductive load and capacitance load.
- 4) Complements the 2SA2073

Applications

Low frequency amplifier High speed switching

Structure

NPN Silicon epitaxial planar transistor

Packaging specifications

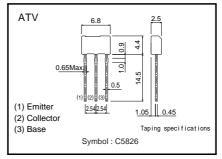
	Package	Taping	
Туре	Code	TV2	
	Basic ordering unit (pieces)	2500	
2SC5826		0	

Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	60	V	
Collector-emitter voltage		Vceo	60	V	
Emitter-base voltage		Vebo	6	V	
Collector current	DC	lc	3	А	
	Pulsed	Іср	6	A *	
Power dissipation		Pc	1.0	W	
Junction temperature		Tj	150	°C	
Range of storage temperature		Tstg	-55 to 150	°C	

*Pw=100ms

•External dimensions (Unit : mm)



Transistors

•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
Collector-emitter breakdown voltage	BVCEO	60	-	-	V	lc=1mA	
Collector-base breakdown voltage	ВУсво	60	-	-	V	Ic=100μA	
Emitter-base breakdown voltage	ВVево	6	-	-	V	Ιε=100μΑ	
Collector cut-off current	Ісво	-	-	1.0	μA	Vcb=40V	
Emitter cut-off current	Іево	-	-	1.0	μΑ	Veb=4V	
Collector-emitter saturation voltage	Vce (sat)	-	200	500	mV	Ic=2A *1	
						IB=0.2A	
DC current gain	hfe	120	-	390	-	Vce=2V	
						Ic=100mA	
	fτ	-	200	.00 –	MHz	Vce=10V *1	
Transition frequency						IE=-100mA	
						f=10MHz	
Corrector output capacitance	Cob			20 –	pF	Vcb=10V	
		_	20			I∈=0mA	
						f=1MHz	
Turn-on time	Ton	_	50	-	ns	Ic=3A *2	
Storage time	Tstg	-	150	-	ns	Ів1=300mA Ів2= –300mA	
Fall time	Tf	_	30	-	ns	Vcc≒25V	

*1 Non repetitive pulse *2 See Switching charactaristics measurement circuits

•hfe RANK

Q	R		
120–270	180–390		

•Electrical characteristic curves

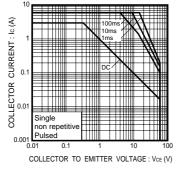
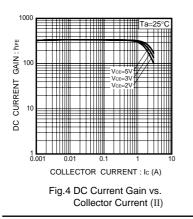
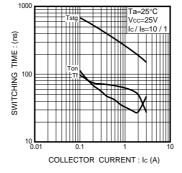


Fig.1 Safe Operating Area



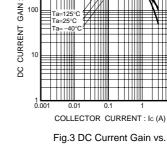




COLLECTOR SATURATION VOLTAGE : V cE (sat) (V)

0.

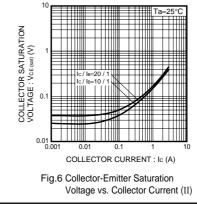
0.01 L



1000

hFE

Collector Current (I)



ROHM

0.

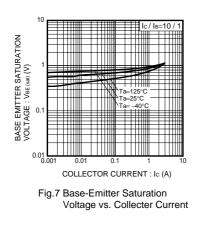
Fig.5 Collector-Emitter Saturation

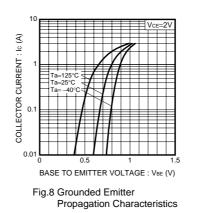
COLLECTOR CURRENT : Ic (A)

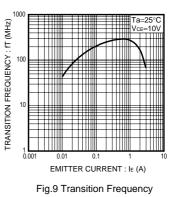
Voltage vs. Collector Current (I)

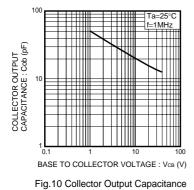
2SC5826

Transistors

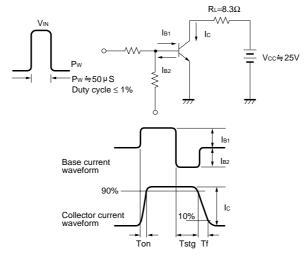












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